

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------|------------------|---------|------------------|
| L4 | 0 | polisilicon with (silicon adj germanium) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/12 15:28 |
| L5 | 968 | polysilicon with (silicon adj germanium) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/12 15:28 |
| L6 | 426 | ((photo adj diode) or photodiode) and (transfer adj transistor) and (floating adj diffusion) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/12 15:28 |
| L7 | 5 | 5 and L6 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/12 15:28 |
| S1 | 1 | 10/656165 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/07/31 11:15 |
| S2 | 2674 | 250/208.1.ccls. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/07/30 09:48 |
| S3 | 315 | ((photo near diode) or photodiode) near gate | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/12 10:25 |
| S4 | 3 | ((photo near diode) or photodiode) near gate near contact | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/07/31 11:36 |
| S5 | 29 | ("3535532" "3914137" "4274104" "4275404" "4366567" "4532694" "4607368" "4608696" "4727556" "4745452" "4766472" "4777516" "4788690" "4794609" "4802182" "4829346" "4845723" "4847665" "4847846").PN. OR ("4995049").URPN. | US-PGPUB; USPAT; USOCR | OR | ON | 2005/07/31 11:41 |

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|-----|-------|----------------------------------------------------------------------------------------------------|---------------------------------------------------------|----|----|------------------|
| S6 | 2515 | 250/214.1.ccls. | US-PGPUB; USPAT; USOCR | OR | ON | 2005/07/31 11:42 |
| S7 | 426 | ((photo adj diode) or photodiode) and (transfer adj transistor) and (floating adj diffusion) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/12 10:26 |
| S8 | 21 | reduce\$2 near pin\$4 near voltage | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/12 10:26 |
| S9 | 126 | reduce\$2 near2 pin\$4 near2 voltage | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/12 10:27 |
| S10 | 1 | S7 and S9 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/12 10:27 |
| S11 | 13636 | pin\$4 near2 voltage | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/12 10:27 |
| S12 | 44 | S7 and S11 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/12 10:29 |
| S13 | 50496 | dielectric and polysilicon | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/12 10:29 |
| S14 | 27 | S12 and S13 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/12 10:34 |
| S15 | 87 | S7 and S13 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/10/12 10:35 |